



MXDLN16UEGPS Low Noise Amplifier Datasheet



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General Description

MXDLN16UE high gain, low noise amplifier(LNA) is dedicated to GPS, GLONASS Galileo and Beidou standards. This product has an extremely low noise figure of 0.7dB, 19dB gain and excellent linearity.

MXDLN16UE works under a 1.2V to 2.85V single power supply while consumes 6mA current, in power down (PD) mode, the power consumption will be reduced to less than 1uA.

MXDLN16UE uses a small 1.1mmx0.9mmx0.45mm LGA 6-pin package.

Applications

Automotive Navigation
 Personal Navigation Device (PND)
 Cell Phone with GPS
 MID/PAD with GPS

Features

- High Gain: 19dB
- Low noise figure 0.7dB @ 1575.42MHz
- Low operation current 6mA & PD current less than 1uA
- 3.6mA current under 1.2V power supply
- Single supply voltage range 1.2V to 2.85V
- Small package 1.1mmx0.9mmx0.45mm
- Low cost BOM
- Lead-Free and RoHS-Compliant

Pin Configuration/Application Diagram (Top view)

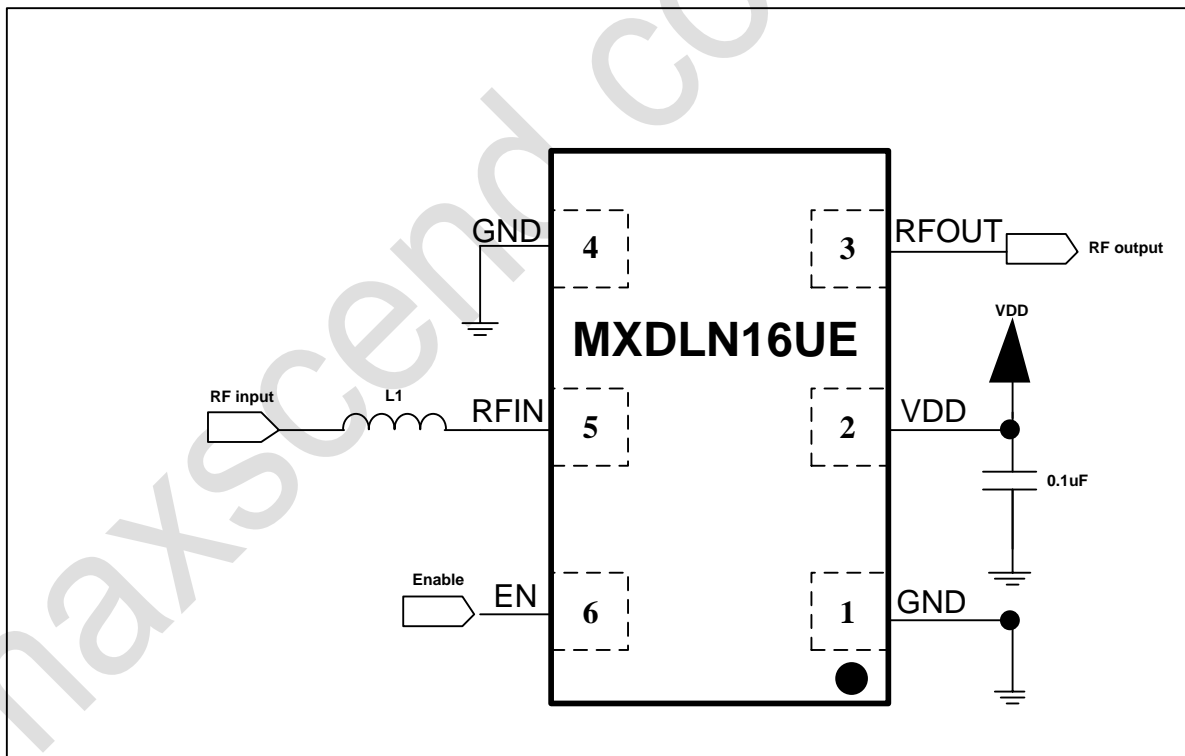


Figure 1. MXDLN16UE application circuit

Table 1.

Component	Vendor	Type	Part Number & value
L1	Murata	Wired inductor, high Q	LQW15AN12N, 12nH
	various	Ceramic inductor, low Q	10nH

Absolute Maximum Ratings

Table 2.

Parameters	Range	Units
Power supply	-0.3 ~ 3	V
Other Pin to GND	-0.3~VDD+0.3	V
Maximum RF Input Power	10	dBm
Operation Temperature Range	-40~85	°C
Junction Temperature	150	°C
Storage temperature Range	-65~160	°C
Lead Temperature (soldering)	260	°C
Soldering Temperature (reflow)	260	°C
Human Body Mode ESD	-2000~+2000	V
Machine Mode ESD	-150~+150	V
Charge Device Mode ESD	-500~+500	V

Specifications

DC Characteristics

Typically T_A=25°C VDD=2.8V, unless otherwise noted

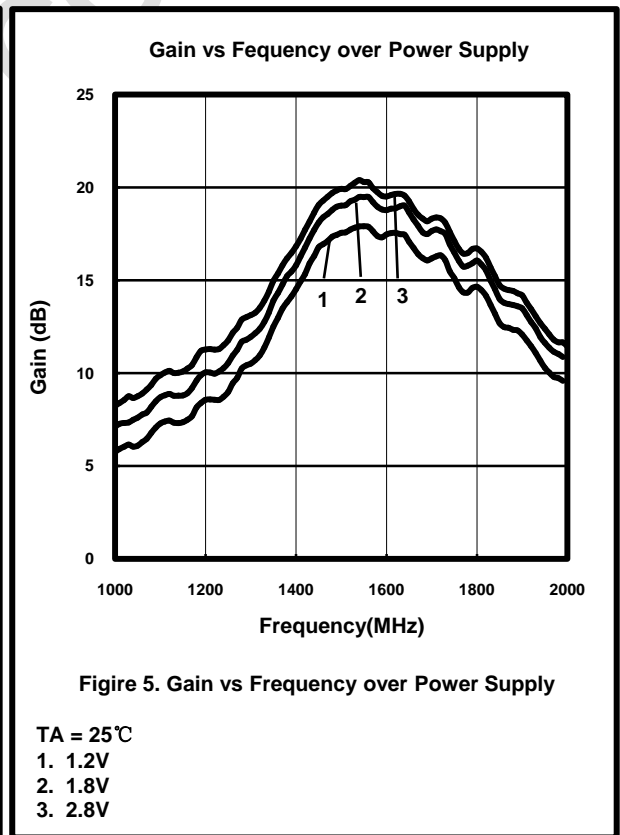
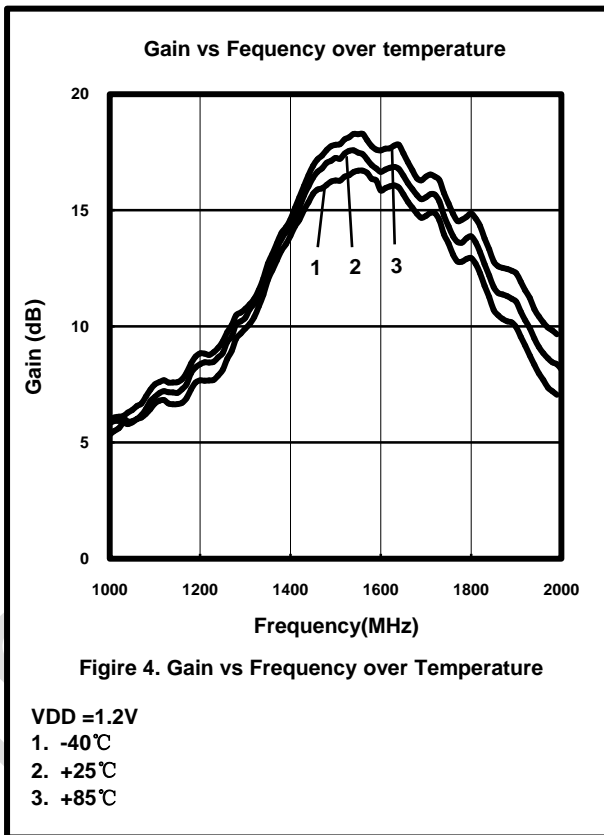
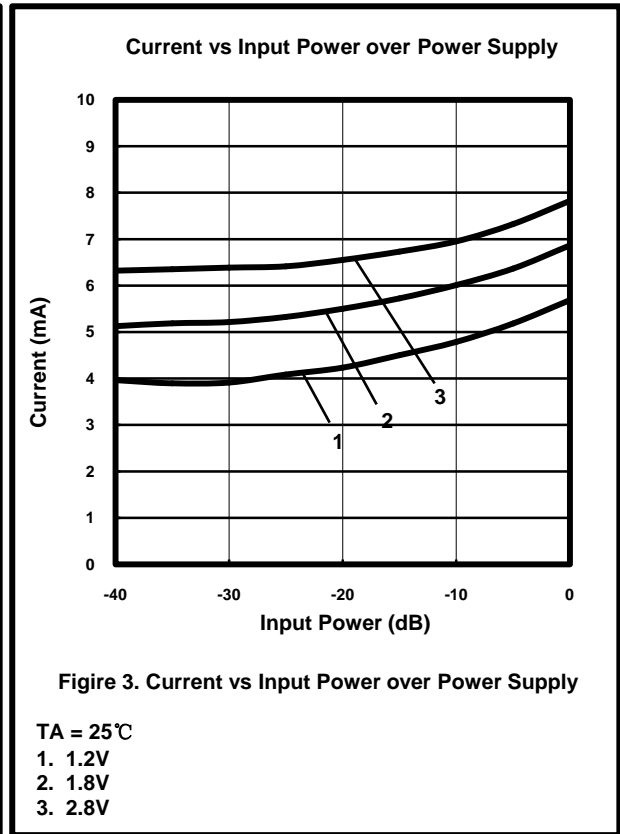
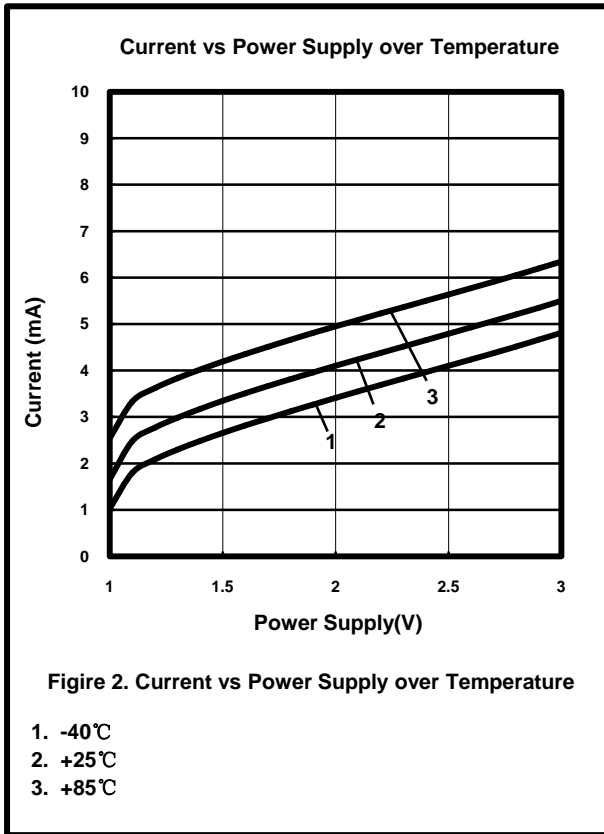
Table 3.

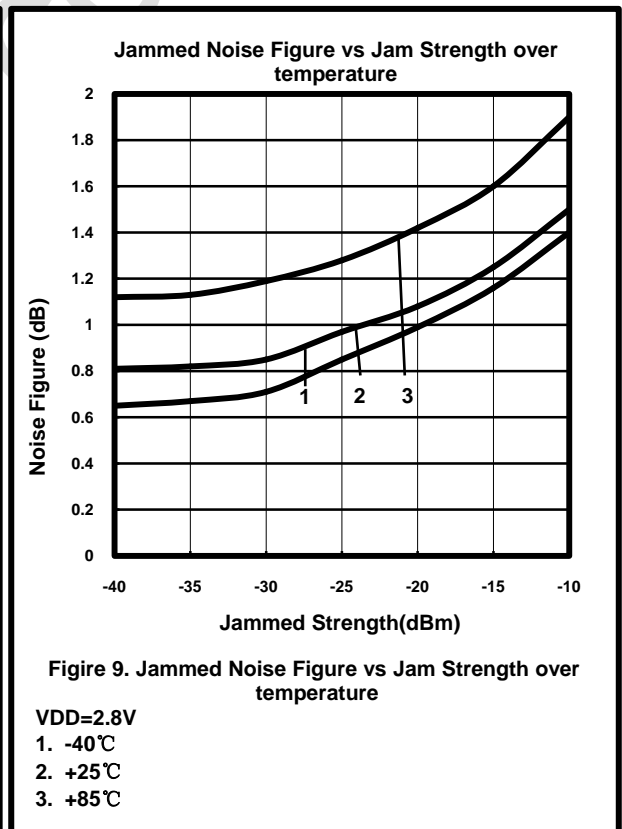
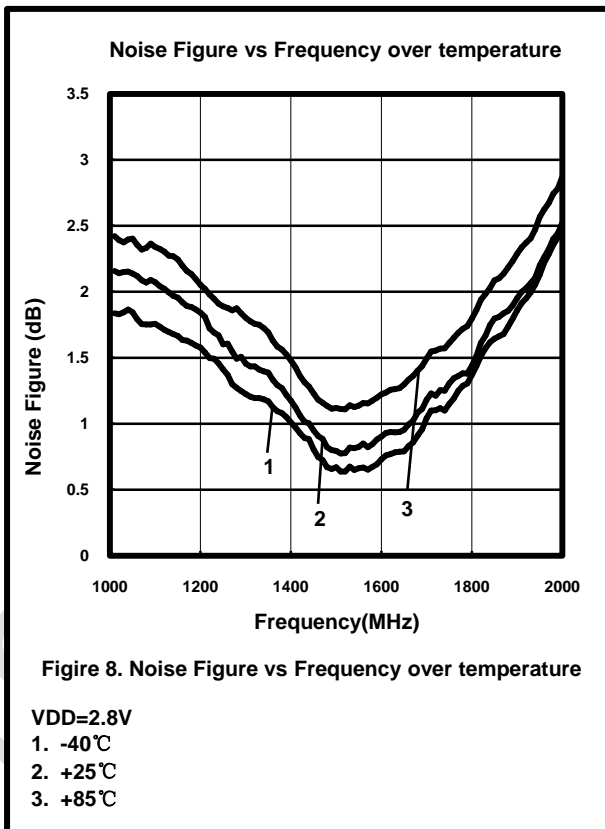
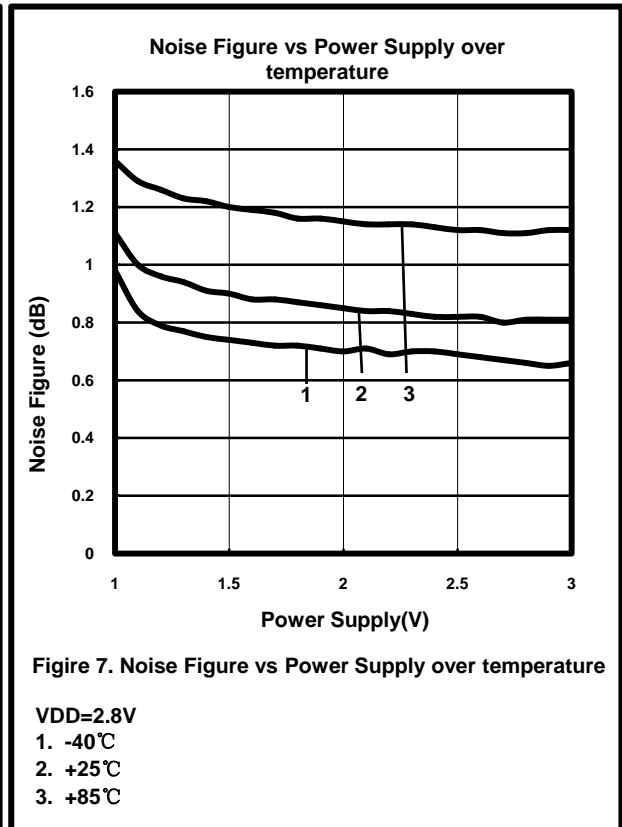
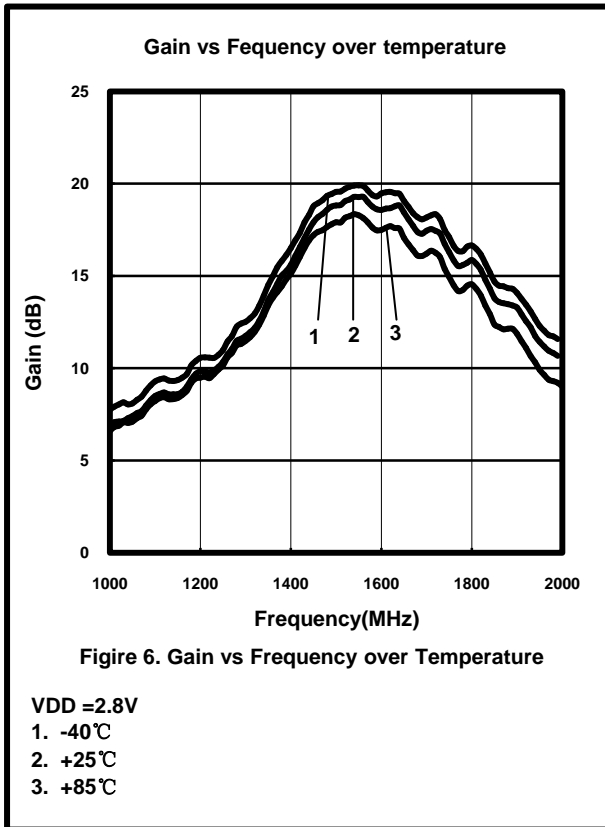
Parameters	Condition	Min	Typ	Max	Units
Supply Voltage		1.1	2.8	2.85	V
Supply Current	EN=High		6		mA
	VDD = 1.2V		3.6		
	EN=Low			1	µA
EN Input High		0.9			V
EN Input Low				0.6	V

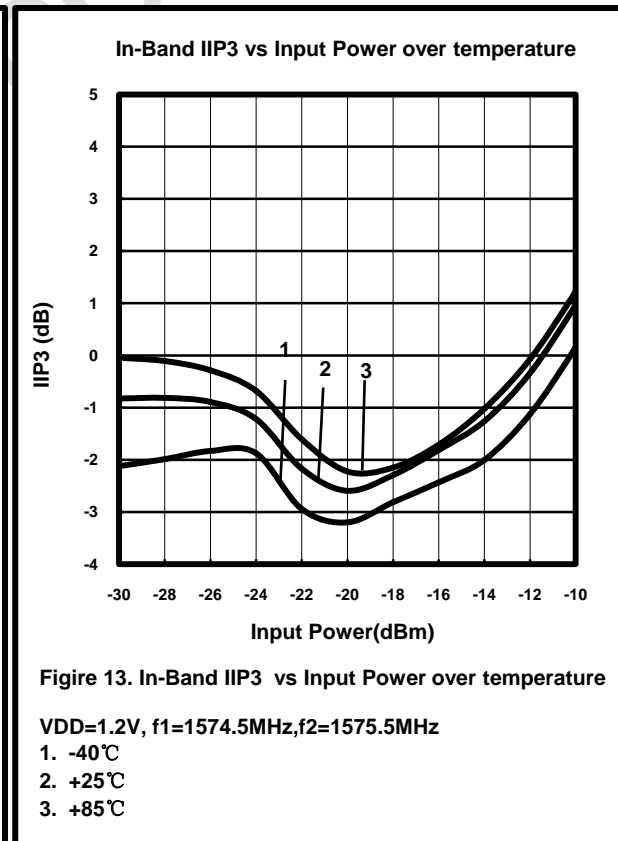
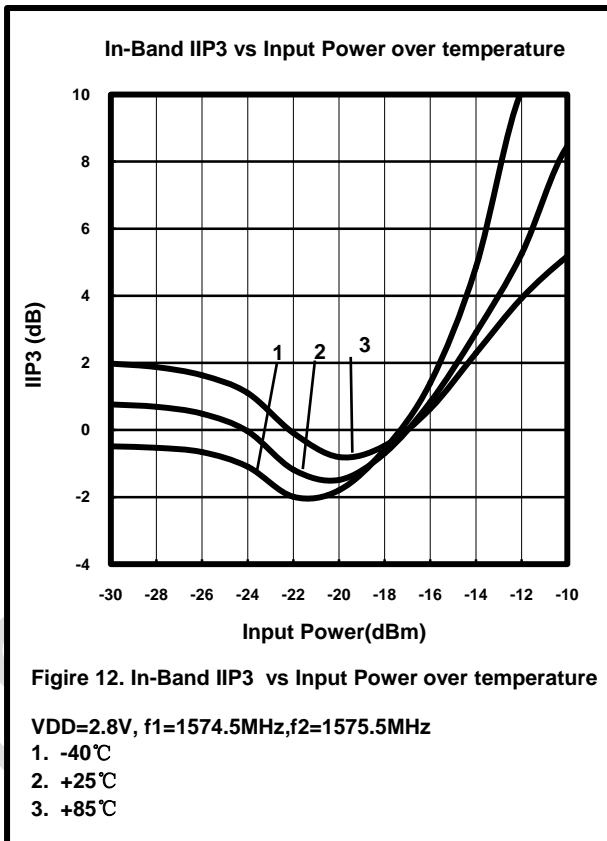
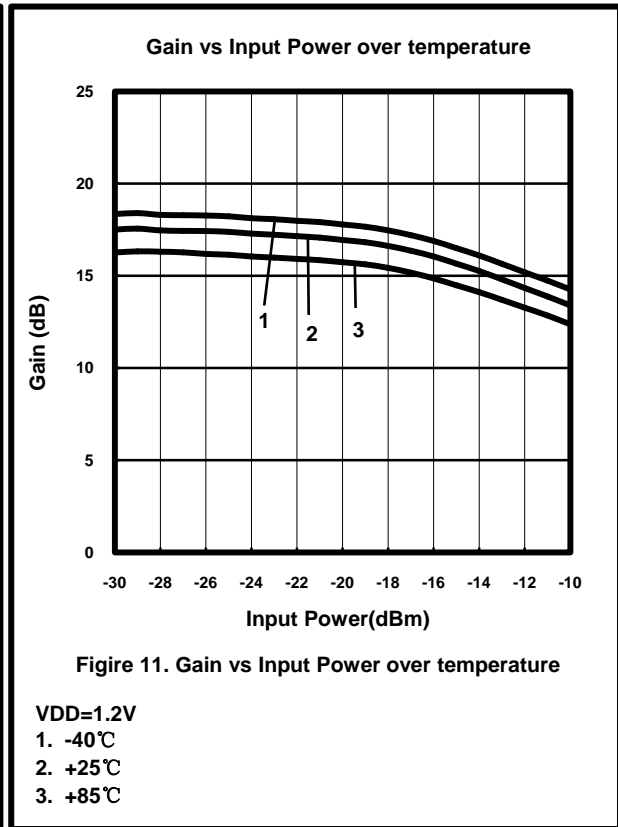
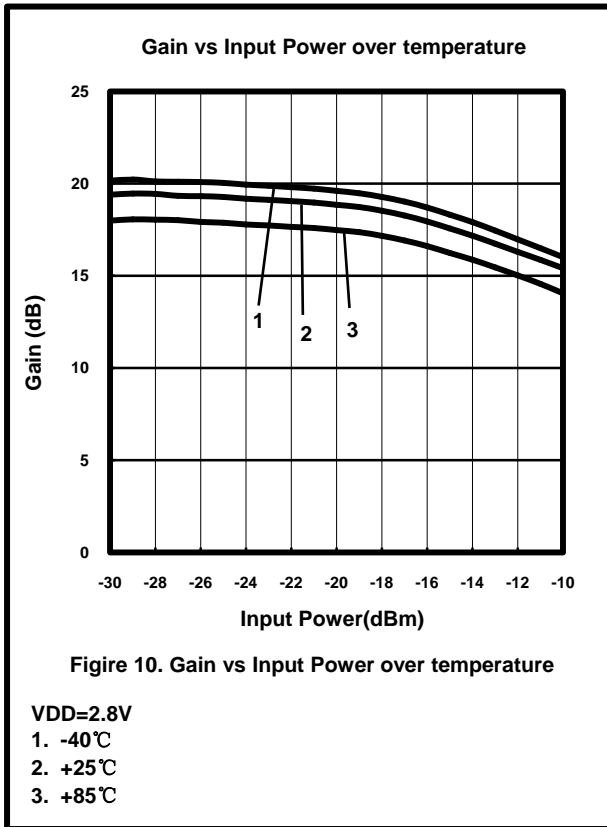
**AC Characteristics**Typically $T_A=25^{\circ}\text{C}$ $V_{DD}=2.8\text{V}$, all data measured on Maxscend's EVB, unless otherwise noted**Table 4.**

Parameters	Conditions	Min	Typ	Max	Units
RF Frequency Range	None		1575.42		MHz
Power Gain			19		dB
	Note7		19		
Noise Figure			0.7		dB
	Note7		0.8		
Input Return Loss	Note1		-12		dB
	Note7		-10		
Output Return Loss	Note1		-12		dB
	Note7		-11		
Reverse Isolation	Note1		-28		dB
VSWR	Note1		1.7		
Jammed Noise Figure	Note2		0.85		dB
Stability	Note3	1.5			
Input Power 1-dB Compression Point	1575MHz		-16		dBm
	900MHz		-13		
	2400MHz		-5		
Input In-Band IP3	Note4		-2		dBm
Input Out-Band IP3	Note5		+15		dBm
Input IP2	Note6		42.8		dBm

Note1: sweep power -30dBm, 1575.42MHz**Note2:** jammed signal @ 1.8GHz & 950MHz, -30dBm**Note3:** frequency range 500MHz-5GHz**Note4:** $f_1 = 1574.5\text{ MHz}$, $f_2 = 1575.5\text{ MHz}$, -30dBm**Note5:** $f_1 = 2400\text{ MHz}$, $f_2 = 2000\text{ MHz}$, -30dBm $IP_3 = \text{pin} - (\text{IM}_3 - \text{Gain}_{1575\text{MHz}}) / 2$ **Note6:** $f_1 = 2475\text{ MHz}$, $f_2 = 900\text{ MHz}$, -30dBm, $IP_2 = \text{pin} - (\text{IM}_2 - \text{Gain}_{1575\text{MHz}})$, IMD2 referred to input port.**Note7:** Beidou frequency range B1: 1559.052MHz---1591.788MHz







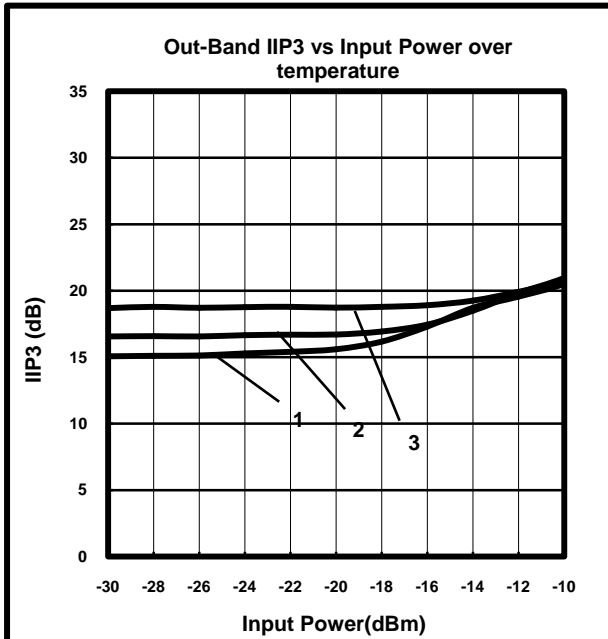


Figure 14. Out-Band IIP3 vs Input Power over temperature

VDD=2.8V, f1=2175MHz, f2=1875MHz
 1. -40°C
 2. +25°C
 3. +85°C

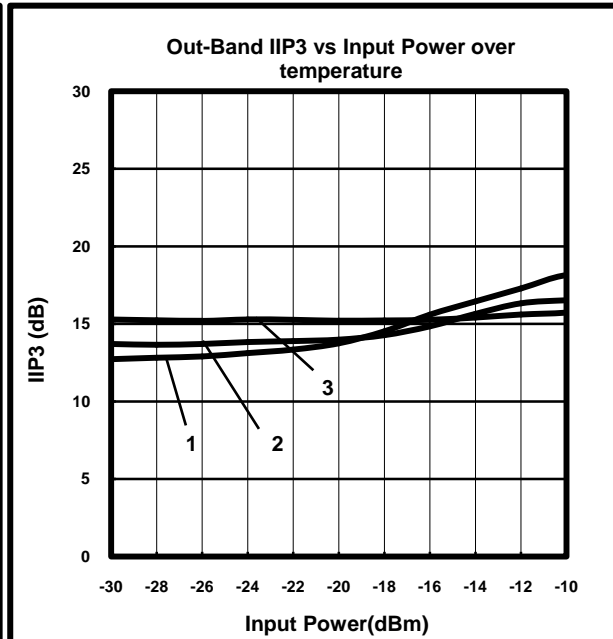


Figure 15. Out-Band IIP3 vs Input Power over temperature

VDD=1.2V, f1=2175MHz, f2=1875MHz
 1. -40°C
 2. +25°C
 3. +85°C

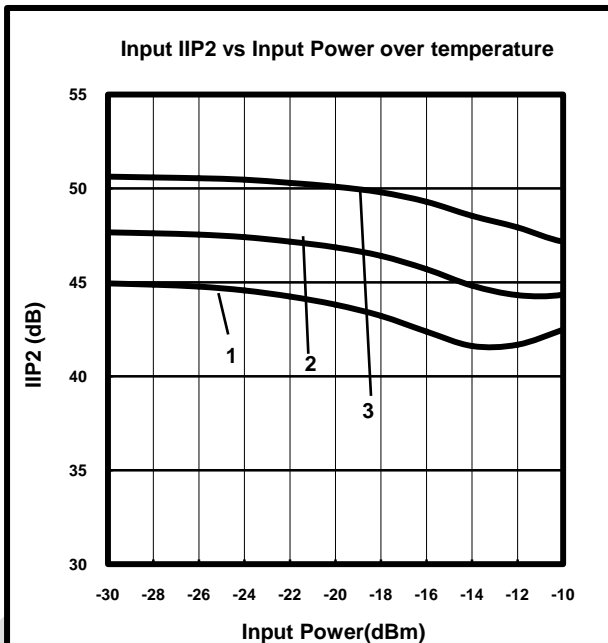


Figure 16. Input IIP2 vs Input Power over temperature

VDD=2.8V, f1=2475MHz, f2=900MHz
 1. -40°C
 2. +25°C
 3. +85°C

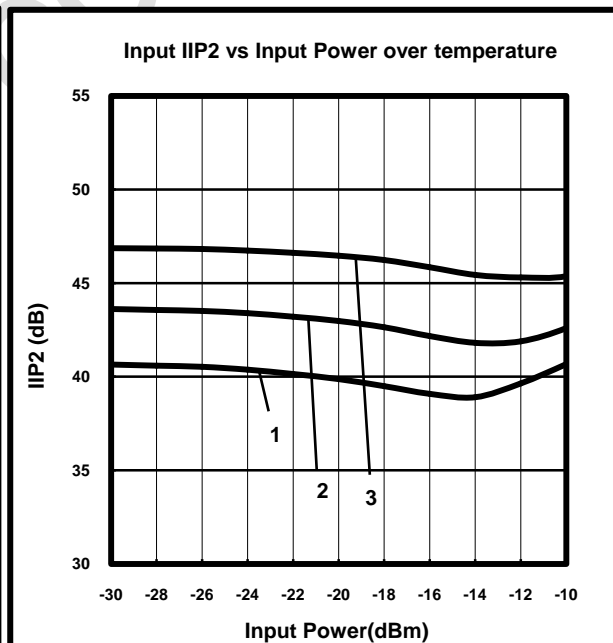
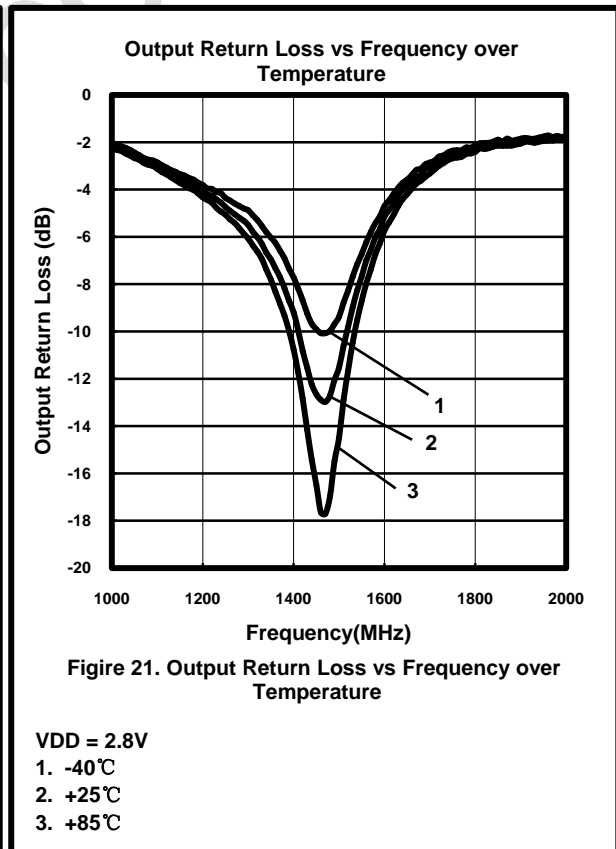
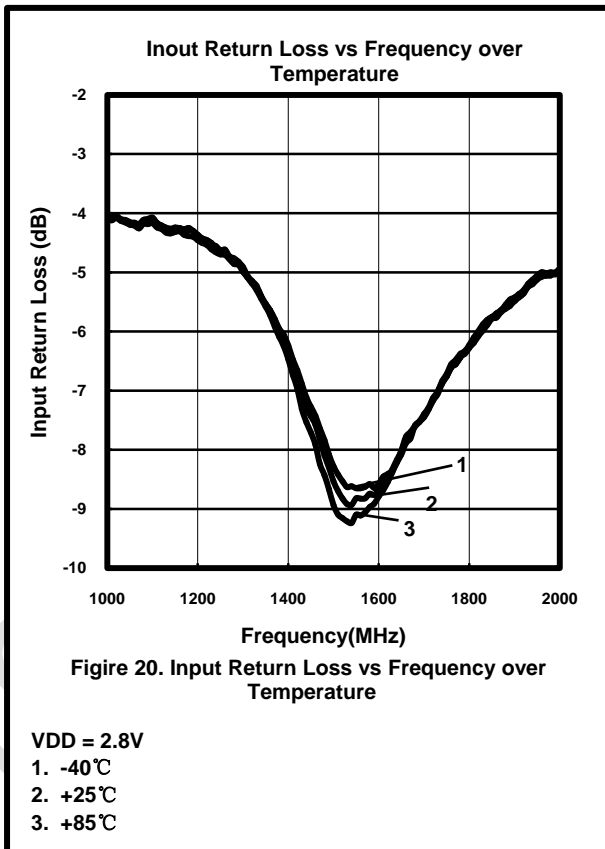
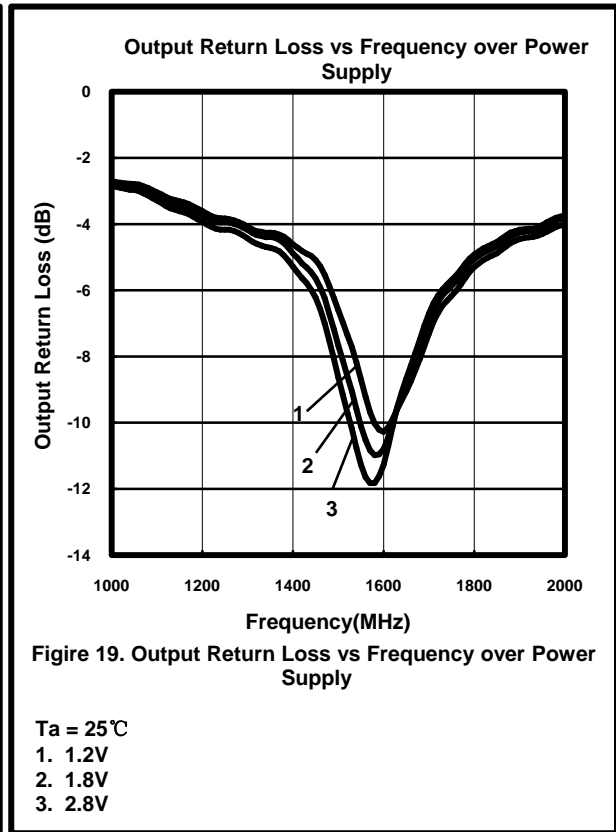
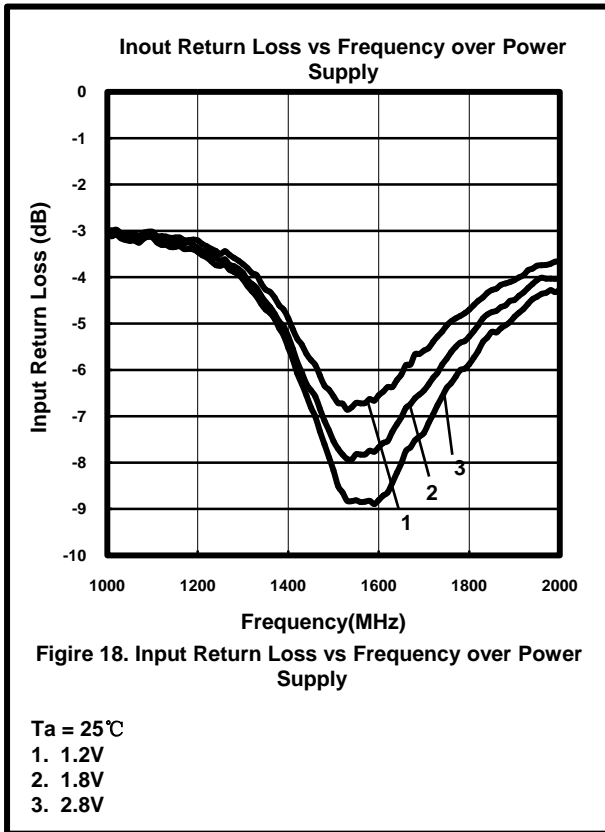
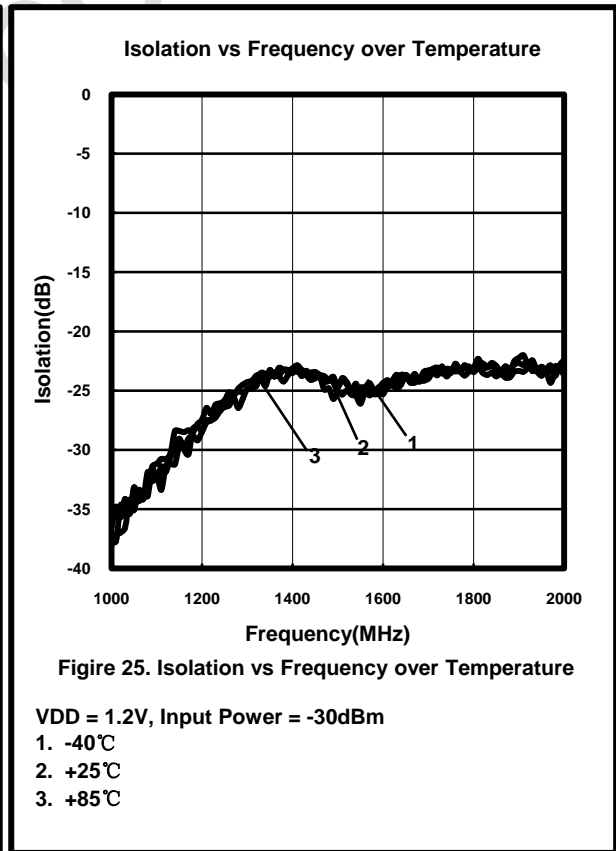
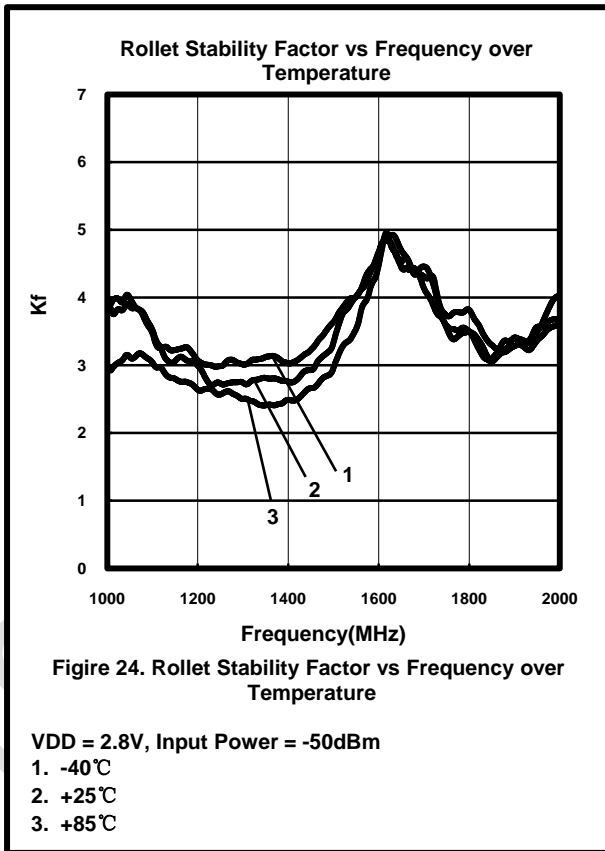
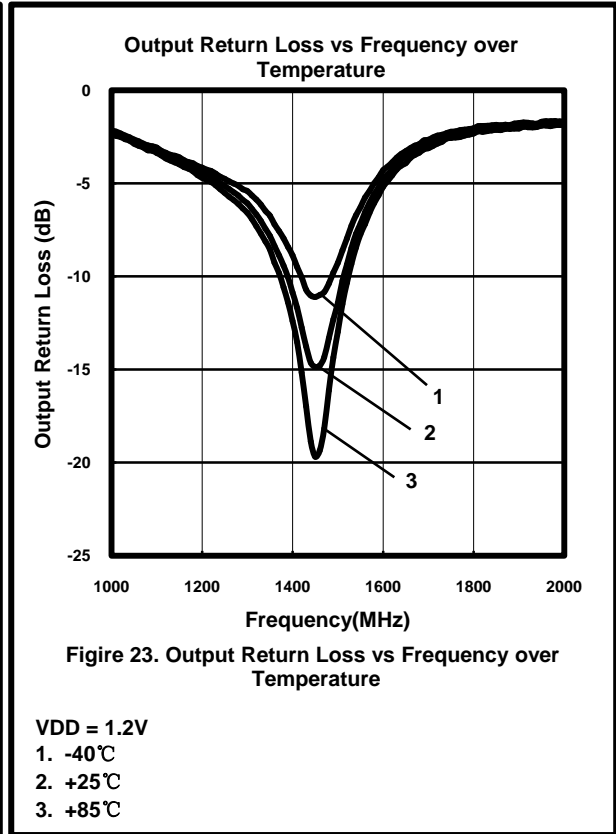
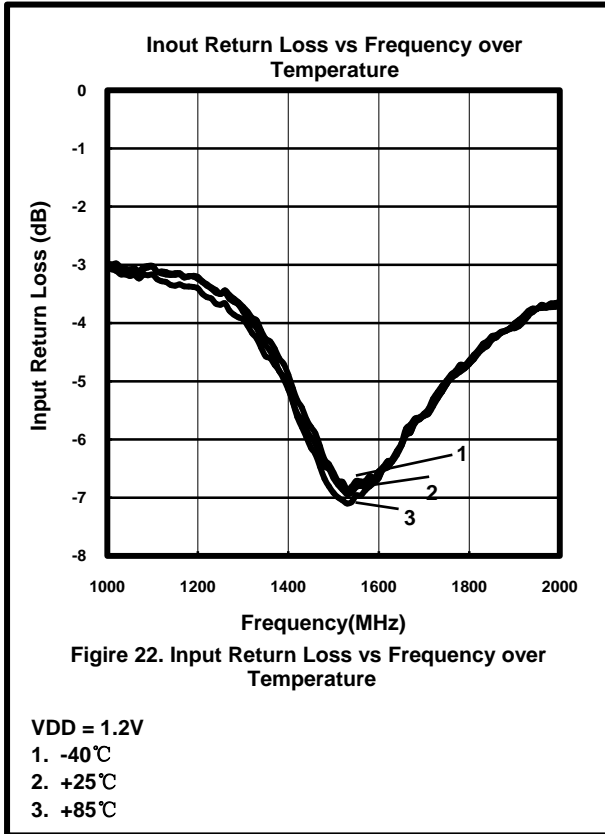
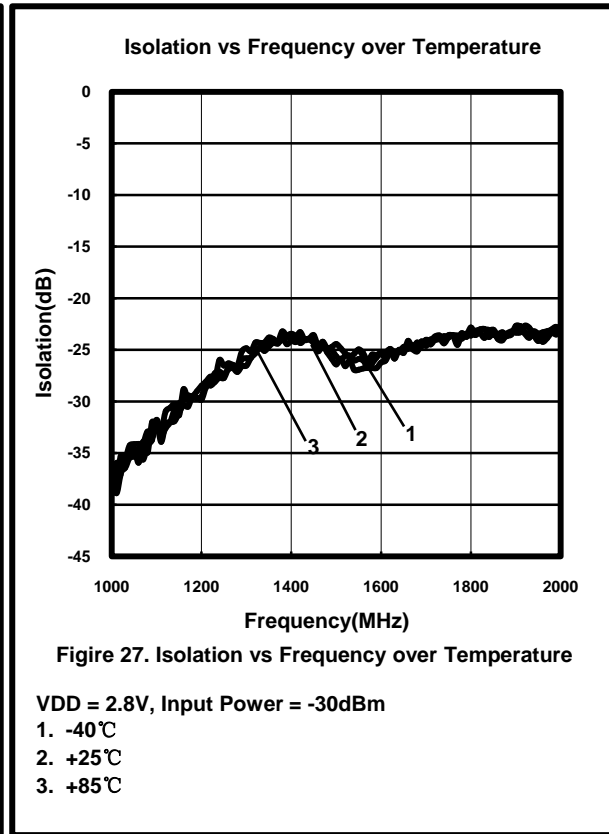
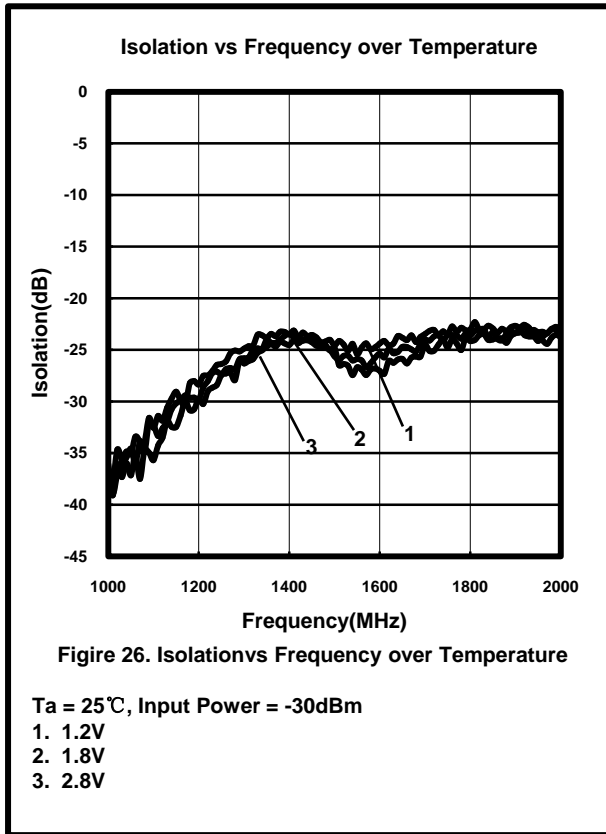


Figure 17. Input IIP2 vs Input Power over temperature

VDD=1.2V, f1=2475MHz, f2=900MHz
 1. -40°C
 2. +25°C
 3. +85°C







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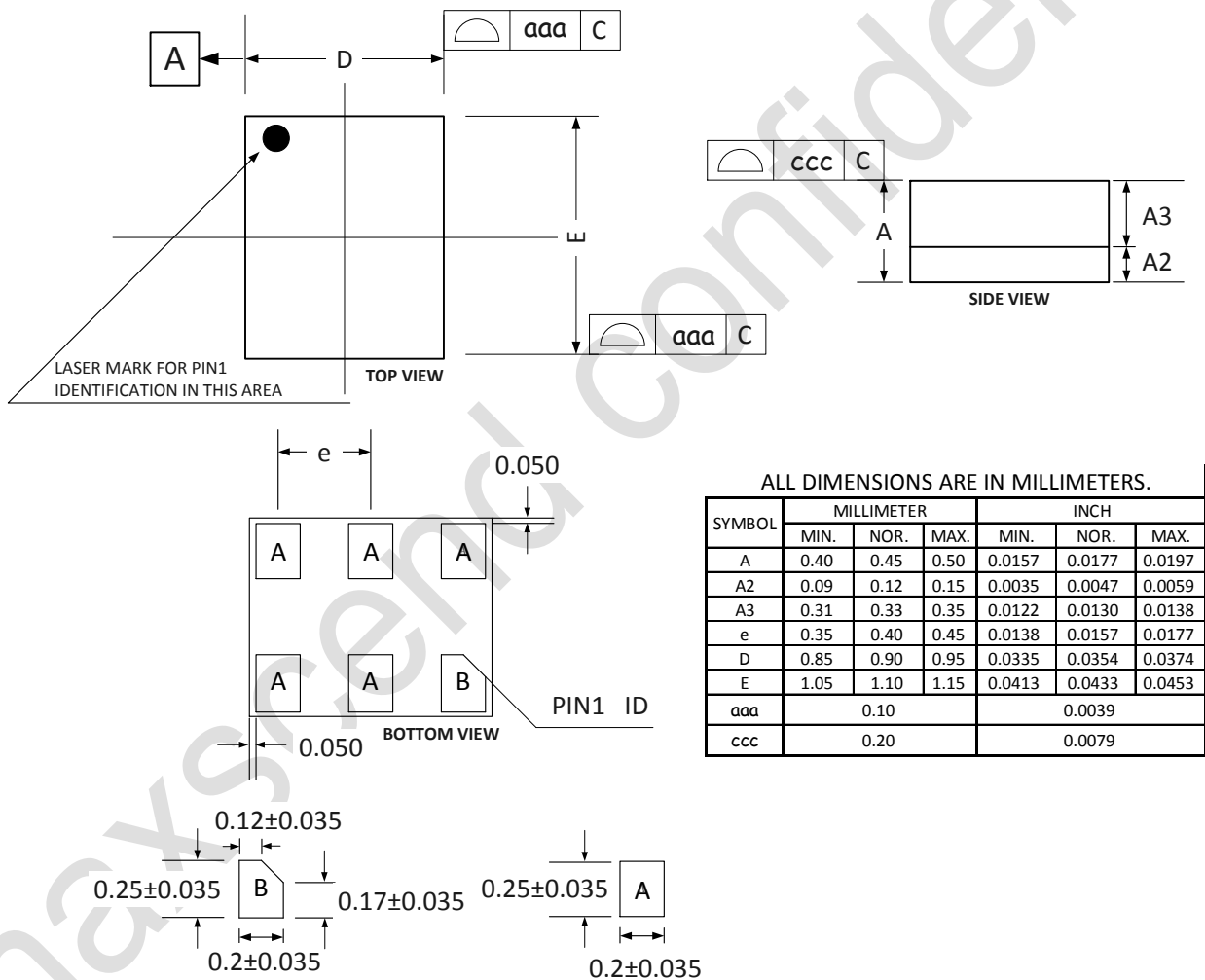
Pin Descriptions

Table 5.

Pin	Pin Name	I/O	Pin Description
1	GND	AG	Analog VSS
2	VDD	AP	Power supply, 1.1~2.85V
3	RFOUT	AO	LNA output
4	GND	AG	Analog VSS
5	RFIN	AI	LNA input from antenna
6	EN	DI	Pull high enable, pull low into power down mode

Note: DI (digital input), DO (digital output), DIO (digital bidirectional), AI (analog input), AO (analog output), AIO (analog bidirectional), AP (analog power), AG (analog ground),

Outline Dimensions


Figure 28. MXDLN16UE outline dimension

Reflow Chart

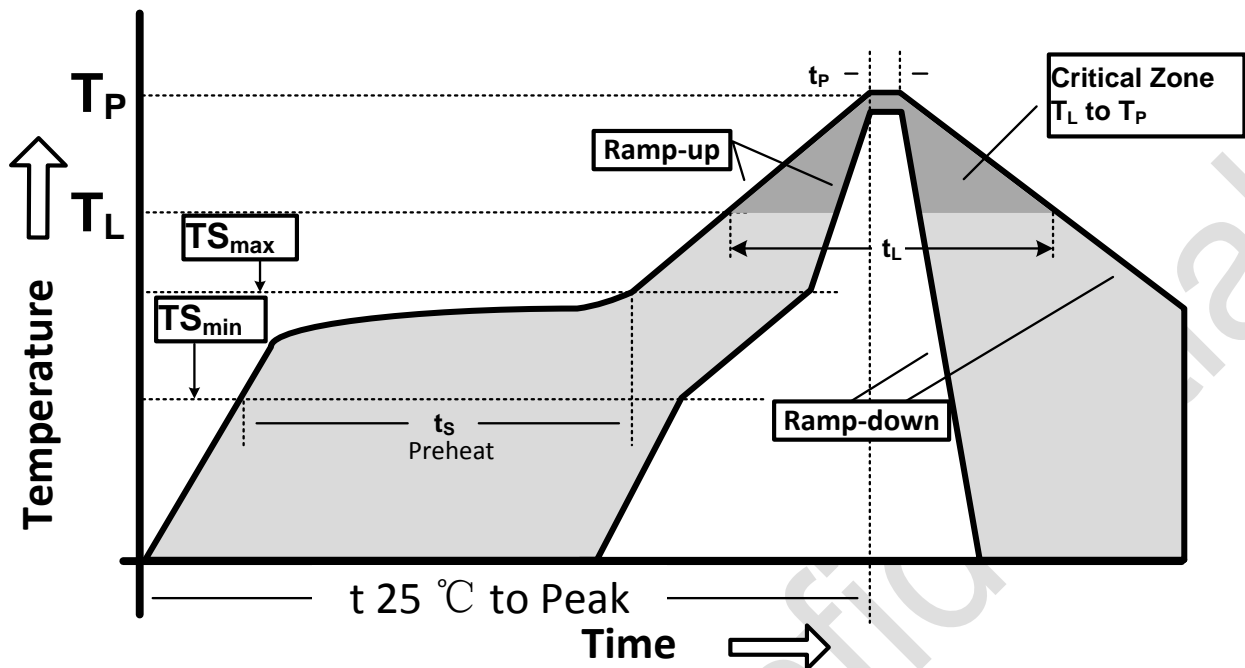


Figure 29. Recommended Lead-Free Reflow Profile

Table 6.

Profile Parameter	Lead-Free Assembly, Convection, IR/Convection
Ramp-up rate (TS_{max} to T_p)	3°C/second max.
Preheat temperature (TS_{min} to TS_{max})	150°C to 200°C
Preheat time (t_s)	60 - 180 seconds
Time above T_L , 217°C (t_L)	60 - 150 seconds
Peak temperature (T_p)	260°C
Time within 5°C of peak temperature (t_p)	20 - 40 seconds
Ramp-down rate	6°C/second max.
Time 25°C to peak temperature	8 minutes max.

ESD Sensitivity

Integrated circuits are ESD sensitive and can be damaged by static electric charge. Proper ESD protection techniques should be used when handling these devices.

RoHS Compliant

This product does not contain lead, mercury, cadmium, hexavalent chromium, polybrominated biphenyls (PBB) and polybrominated diphenyl ethers (PBDE), and are considered RoHS compliant.